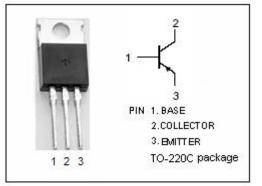


isc Silicon PNP Power Transistor

2SB683

DESCRIPTION

- Collector-Emitter Breakdown Voltage-
- : V_{(BR)CEO} = -100V(Min)
- High Power Dissipation
- Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

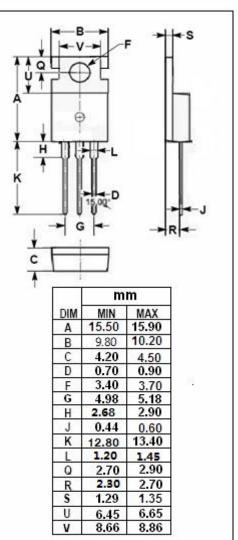


APPLICATIONS

• Designed for low frequency power amplifier applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL | PARAMETER | VALUE | UNIT | |
|------------------|--|-------|------|--|
| V _{сво} | Collector-Base Voltage | -100 | V | |
| V _{CEO} | Collector-Emitter Voltage | -100 | V | |
| V _{EBO} | Emitter-Base Voltage | -5 | V | |
| lc | Collector Current-Continuous | -5 | A | |
| | Total Power Dissipation @ $T_a=25^{\circ}C$ | 1.5 | 147 | |
| Pc | Total Power Dissipation @ T _c =25℃ | 40 | - W | |
| TJ | Junction Temperature 150 | | °C | |
| T _{stg} | Storage Temperature Range -40~150 | | °C | |





isc Silicon PNP Power Transistor

2SB683

ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | МАХ | UNIT |
|----------------------|--------------------------------------|--|------|------|------|------|
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage | I _c = -10mA; R _{BE} = ∞ | -100 | | | V |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | I _E = -5mA; I _C = 0 | -5 | | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = -4A; I _B = -0.4A | | | -1.7 | V |
| V _{BE(on)} | Base-Emitter On Voltage | I _C = -4A; V _{CE} = -5V | | | -1.5 | V |
| Ісво | Collector Cutoff Current | V _{CB} = -100V; I _E = 0 | | | -30 | μA |
| Iceo | Collector Cutoff Current | V _{CE} = -100V; R _{BE} = ∞ | | | -0.1 | mA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = -4V; I _C = 0 | | | -0.1 | mA |
| h _{FE-1} | DC Current Gain | Ic= -1A; Vce= -5V | 55 | | 300 | |
| h _{FE-2} | DC Current Gain | I _C = -4A; V _{CE} = -5V | 15 | | | |

h_{FE-1} Classifications

| С | D | E |
|--------|--------|---------|
| 55-110 | 90-180 | 150-300 |

NOTICE:

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